

NX6350EP Series

LASER DIODE

1 270/1 290/1 310/1 330 nm AlGainAs MQW-DFB LASER DIODE FOR 40GBASE-LR4 APPLICATION

R08DS0066EJ0100 Rev.1.00 Aug 14, 2012

DESCRIPTION

The NX6350EP series is a 1 270/1 290/1 310/1 330 nm Multiple Quantum Well (MQW) structured Distributed Feed-Back (DFB) laser diode with InGaAs monitor PIN-PD.

APPLICATIONS

- 40GBASE-LR4
- Bi-Directional 10G SFP+ (CPRI,10G-Ethernet)

FEATURES

 $\begin{array}{ll} \bullet & \text{Optical output power} & P_O = 8.5 \text{ mW} \\ \bullet & \text{Low threshold current} & I_{th} = 8 \text{ mA} \\ \bullet & \text{Differential efficiency} & \eta_d = 0.35 \text{ W/A} \\ \end{array}$

Wide operating temperature range

• InGaAs monitor PIN-PD

CAN packageFocal point

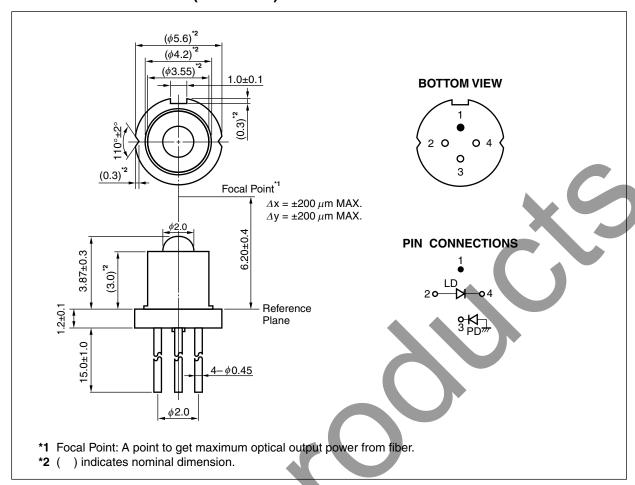
φ 5.6 mm 6.2 mm

 $T_C = -5 \text{ to } +85^{\circ}\text{C}$





PACKAGE DIMENSIONS (UNIT: mm)



ORDERING INFORMATION

Part Number	Package	Pin Connections
NX6350EPxx*1	4-pin CAN with ball lens cap	1
		20 LD 04
		∘ K 3 _{PD} <i>m</i>

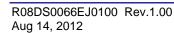
Note: *1. The last two digits ("xx") of Part Number indicates Wavelength Code.

The relationships between the code and wavelength are as follows.

WAVELENGTH CODE	WAVELENGTH (nm)
27	1 270
29	1 290
31	1 310
33	1 330

Remarks 1. The color of lens cap might be observed differently.

2. The hermetic test will be performed as AQL 1.0%.





ABSOLUTE MAXIMUM RATINGS (T_A = 25°C, unless otherwise specified)

Parameter	Symbol	Ratings	Unit
Optical Output Power	Po	15	mW
Forward Current of LD	I _F	120	mA
Reverse Voltage of LD	V_R	2.0	V
Forward Current of PD	I _F	10.0	mA
Reverse Voltage of PD	V_R	15	V
Operating Case Temperature	T _C	−5 to +85	°C
Storage Temperature	T _{stg}	−40 to +95	°C
Lead Soldering Temperature	T _{sld}	350 (3 sec.)	°C
Relative Humidity (noncondensing)	RH	85	%

RECOMMENDED LD DRIVE CURRENT AT MODULE LEVEL

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Bias Current	I _{bias}	T _C = 25°C	I	30	-	mA

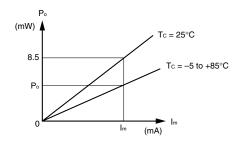
ELECTRO-OPTICAL CHARACTERISTICS

$(T_C = -5 \text{ to } +85^{\circ}\text{C}, \text{CW}, \text{BOL}, \text{ unless otherwise specified})$

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Signaling Rate			-	10.3125	_	Gb/s
Optical Output Power	Po		-	8.5	_	mW
Operating Voltage	V _{op}	P ₀ = 8.5 mW		_	1.8	V
Threshold Current	I _{th}	T _C = 25°C	-	8	15	mA
			_	_	30	
Differential Efficiency	η_{d}	$P_0 = 8.5 \text{ mW}, T_C = 25^{\circ}\text{C}$	0.28	0.35	-	W/A
		$P_0 = 8.5 \text{ mW}$	0.16	_	-	
Peak Emission Wavelength	λ_{p}	$P_0 = 8.5 \text{ mW}$ NX6350EP27	1 264.5	_	1 277.5	nm
		NX6350EP29	1 284.5	_	1 297.5	
		NX6350EP31	1 304.5	-	1 317.5	
		NX6350EP33	1 324.5	=	1 337.5	
Side Mode Suppression Ratio	SMSR	$P_0 = 8.5 \text{ mW}$	35	_	ı	dB
Rise Time	t _r	20-80% ^{*1}	_	_	50	ps
Fall Time	t _f	80-20% ^{*1}	-	_	50	ps
Monitor Current	I _m	$V_R = 1.5 \text{ V}, P_O = 8.5 \text{ mW}$	100	_	1 000	μА
Monitor Dark Current	I _D	V _R = 3.3 V, T _C = 25°C	-	_	10	nA
		V _R = 3.3 V	_	_	100	
Monitor PD Terminal Capacitance	Ct	V _R = 3.3 V, f = 1 MHz	-	-	20	pF
Tracking Error *2	γ	$I_m = const.$ (@P _O = 8.5 mW, T _C = 25°C)	-0.9	-	0.9	dB

Notes: 1. 10.3125 Gb/s, PRBS $2^{31} - 1$, NRZ, Duty Cycle = 50%

2. Tracking Error: γ



$$\gamma = \left| 10 \log \frac{P_o}{8.5} \right| [dB]$$

SAFETY INFORMATION ON THIS PRODUCT



SEMICONDUCTOR LASER



AVOID EXPOSURE-Invisible Laser Radiation is emitted from this aperture

Warning Laser Beam	A laser beam is emitted from this diode during operation. The laser beam, visible or invisible, directly or indirectly, may cause injury to the eye or loss of eyesight. • Do not look directly into the laser beam. • Avoid exposure to the laser beam, any reflected or collimated beam.
Caution GaAs Products	This product uses gallium arsenide (GaAs). GaAs vapor and powder are hazardous to human health if inhaled or ingested, so please observe the following points. • Follow related laws and ordinances when disposing of the product. If there are no applicable laws
	 and/or ordinances, dispose of the product as recommended below. 1. Commission a disposal company able to (with a license to) collect, transport and dispose of materials that contain arsenic and other such industrial waste materials.
	 2. Exclude the product from general industrial waste and household garbage, and ensure that the product is controlled (as industrial waste subject to special control) up until final disposal. Do not burn, destroy, cut, crush, or chemically dissolve the product. Do not lick the product or in any way allow it to enter the mouth.



Revision History

NX6350EP Series Data Sheet

		Description		
Rev.	Date	Page	Summary	
1.00	Aug 14, 2012	_	First edition issued	



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